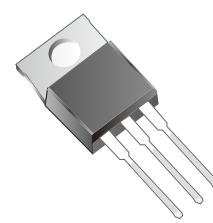


CMS61P06CT-HF

P-Channel
RoHS Device
Halogen Free



Features

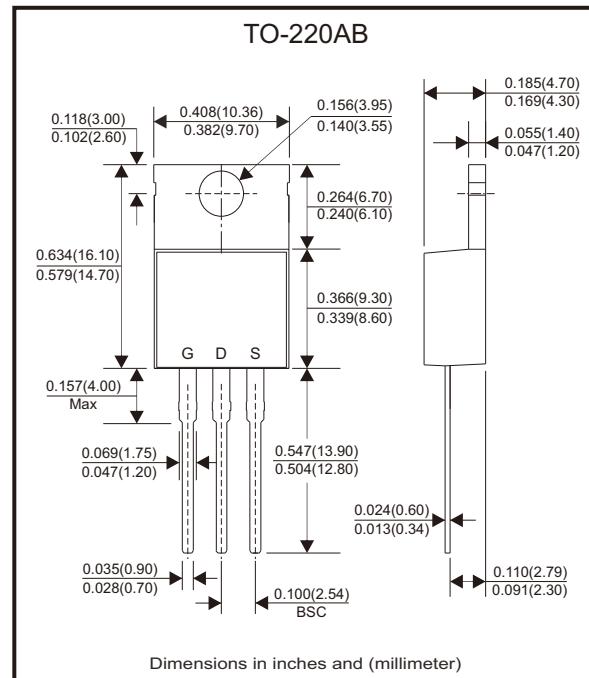
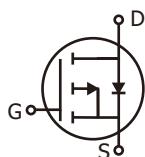
- Advanced DMOS trench technology.
- Improved dv/dt capability.
- Green device available.
- Fast switching.
- 100% EAS guaranteed.

Mechanical data

- Case: TO-220AB, molded plastic.

Circuit diagram

- G : Gate
- S : Source
- D : Drain



Maximum Ratings

Parameter	Conditions	Symbol	Value	Unit
Drain-source voltage		V _{DS}	-60	V
Gate-source voltage		V _{GS}	±20	V
Continuous drain current (Note 1)	I _D @ T _c = 25°C		-61	A
	I _D @ T _c = 100°C		-38.6	
Pulsed drain current (Note 1, 2)		I _{DM}	-244	A
Total power dissipation (Note 4)	P _D @ T _c = 25°C		171	W
	P _D @ T _A = 25°C		2	
Single pulse avalanche energy, L=0.1mH (Note 3)		E _A	245	mJ
Single pulse avalanche current, L=0.1mH (Note 3)		I _A	-70	A
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150	°C
Thermal resistance junction-ambient (Note 1)	Steady state	R _{θJA}	62.5	°C/W
Thermal resistance junction-case (Note 1)	Steady state	R _{θJC}	0.73	°C/W

Electrical Characteristics (at $T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source breakdown voltage	BV_{DSS}	$\text{V}_{\text{GS}} = 0\text{V}, \text{I}_D = -250\mu\text{A}$	-60			V
Gate threshold voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}} = \text{V}_{\text{GS}}, \text{I}_D = -250\mu\text{A}$	-2.0	-3.0	-4.0	
Gate-source leakage current	I_{GSS}	$\text{V}_{\text{GS}} = \pm 20\text{V}$			± 100	nA
Drain-source leakage current ($T_J=25^\circ\text{C}$)	I_{DSS}	$\text{V}_{\text{DS}} = -60\text{V}, \text{V}_{\text{GS}} = 0\text{V}$			-1	μA
Drain-source leakage current ($T_J=85^\circ\text{C}$)		$\text{V}_{\text{DS}} = -48\text{V}, \text{V}_{\text{GS}} = 0\text{V}$			-10	
Static drain-source on-resistance (Note 2)	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}} = -10\text{V}, \text{I}_D = -30\text{A}$			22	$\text{m}\Omega$
		$\text{V}_{\text{GS}} = -6\text{V}, \text{I}_D = -10\text{A}$			40	
Total gate charge (Note 2)	Q_g	$\text{I}_D = -10\text{A}, \text{V}_{\text{DS}} = -48\text{V}, \text{V}_{\text{GS}} = -10\text{V}$		37.2		nC
Gate-source charge	Q_{gs}			10.4		
Gate-drain ("miller") charge	Q_{gd}			10.5		
Turn-on delay time (Note 2)	$\text{t}_{\text{d(on)}}$	$\text{V}_{\text{DD}} = -48\text{V}, \text{I}_D = -5\text{A}$ $\text{V}_{\text{GS}} = -10\text{V}, \text{R}_G = 25\Omega$		23		nS
Rise time	t_r			76		
Turn-off delay time	$\text{t}_{\text{d(off)}}$			113		
Fall time	t_f			29		
Input capacitance	C_{iss}	$\text{V}_{\text{GS}} = 0\text{V}, \text{V}_{\text{DS}} = -25\text{V}, \text{f} = 1\text{MHz}$		2165		pF
Output capacitance	C_{oss}			318		
Reverse transfer capacitance	C_{rss}			102		
Source-drain diode						
Diode forward voltage (Note 2)	V_{SD}	$\text{I}_S = -30\text{A}, \text{V}_{\text{GS}} = 0\text{V}, \text{T}_J=25^\circ\text{C}$			-1.2	V
Continuous source current (Note 1, 6)	I_S	$\text{V}_G = \text{V}_D = 0\text{V}, \text{Force current}$			-61	A
Pulsed source current (Note 2, 6)	I_{SM}				-122	A
Guaranteed avalanche characteristics						
Single pulse avalanche energy (Note 5)	EAS	$\text{V}_{\text{DD}} = -30\text{V}, \text{L}=0.1\text{mH}, \text{IAS} = -30\text{A}$	45			mJ

Notes: 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2 oz copper.

2. The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

3. The EAS data shows max. rating. The test condition is $\text{V}_{\text{DD}}=-30\text{V}, \text{V}_{\text{GS}}=-10\text{V}, \text{L}=0.1\text{mH}, \text{IAS}=-70\text{A}$.

4. The power dissipation is limited by 150°C junction temperature.

5. The min. value is 100% EAS tested guarantee.

6. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

Rating and Characteristic Curves (CMS61P06CT-HF)

Fig.1 - Drain Current vs. T_c

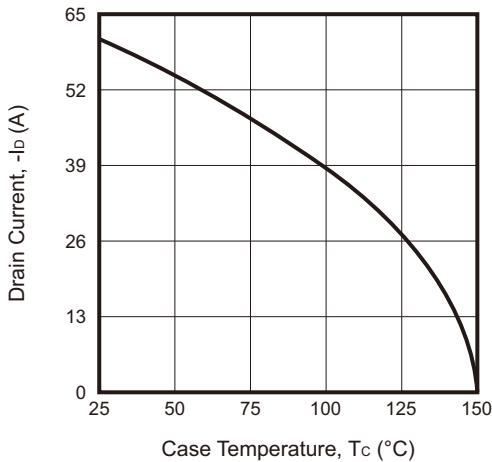


Fig.2 - Gate Charge Characteristics

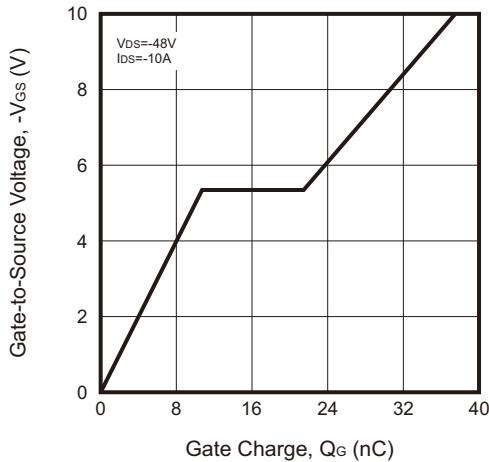


Fig.3 - Normalized $V_{GS(th)}$ vs. T_J

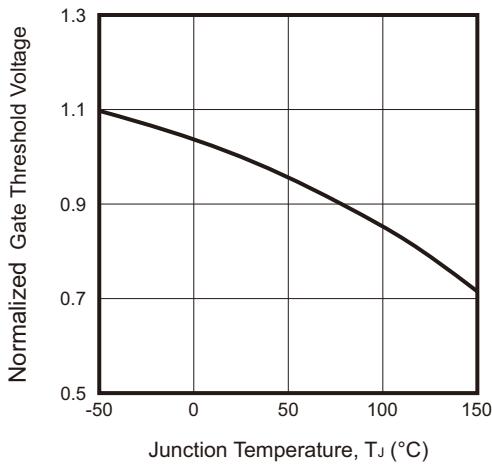


Fig.4 - Normalized $R_{DS(ON)}$ vs. T_J

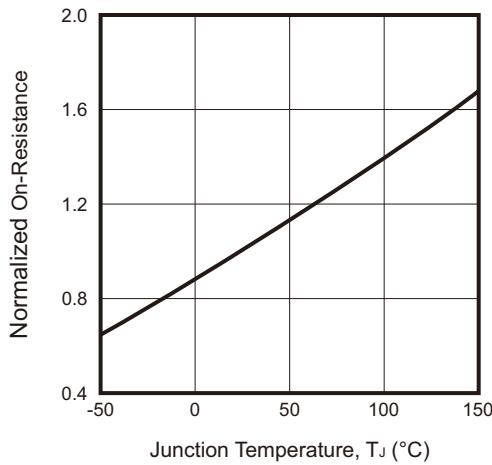
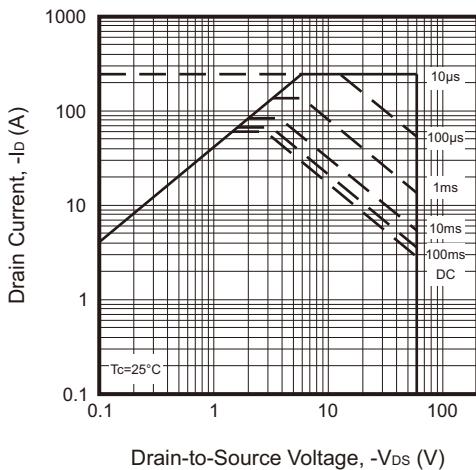


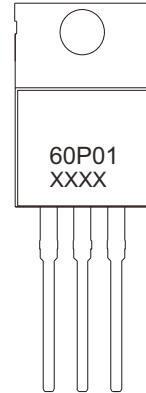
Fig.5 - Safe Operating Area



Company reserves the right to improve product design , functions and reliability without notice.

Marking Code

Part Number	Marking Code
CMS61P06CT-HF	60P01



XXXX = Control code

Standard Packaging

Case Type	TUBE PACK
	TUBE (pcs)
TO-220AB	50